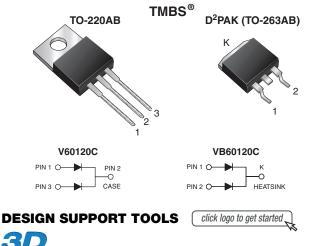
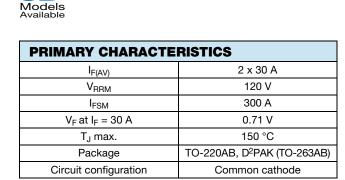
# V60120C, VB60120C

Vishay General Semiconductor

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.41$  V at  $I_F = 5$  A





#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Low thermal resistance

## RoHS

- Meets MSL level 1, per J-STD-020, COMPLIANT LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB package)
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

## **MECHANICAL DATA**

Case: TO-220AB and D<sup>2</sup>PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

#### Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER		SYMBOL	V60120C	VB60120C	UNIT		
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	120		V		
Maximum average forward rectified current (fig. 1)	per device	I	60		A		
	per diode	I <sub>F(AV)</sub>	30				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	300		А		
Non-repetitive avalanche energy at $T_J$ = 25 °C, L = 100 mH per diode		E <sub>AS</sub>	260		mJ		
Peak repetitive reverse current at $t_p = 2 \ \mu s$ , 1 kHz, T <sub>J</sub> = 38 °C ± 2 °C per diode		I <sub>RRM</sub>	0.5		А		
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000		V/µs		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-40 to +150		°C		









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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	I <sub>R</sub> = 1.0 mA	T <sub>A</sub> = 25 °C	V <sub>BR</sub>	120 (minimum)	-	V		
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub> (1)	0.48	-	V		
	I <sub>F</sub> = 15 A			0.66	-			
	I <sub>F</sub> = 30 A			0.88	0.95			
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.41	-			
	I <sub>F</sub> = 15 A			0.58	-			
	I <sub>F</sub> = 30 A			0.71	0.75			
Reverse current at rated $V_{\rm R}$ per diode	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	14	-	μA		
		T <sub>A</sub> = 125 °C		11	-	mA		
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 25 °C		40	500	μA		
	$v_{\rm R} = 120$ V	T <sub>A</sub> = 125 °C		15	45	mA		

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	V60120C	VB60120C	UNIT		
Typical thermal resistance per diode	$R_{ ext{ heta}JC}$	2.2	2.2	°C/W		

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V60120C-E3/4W	1.89	4W	50/tube	Tube		
TO-263AB	VB60120C-E3/4W	1.38	4W	50/tube	Tube		
TO-263AB	VB60120C-E3/8W	1.38	8W	800/reel	Tape and reel		

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

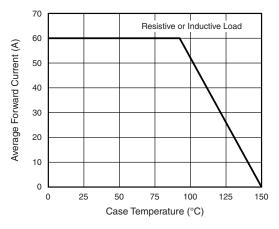


Fig. 1 - Forward Current Derating Curve

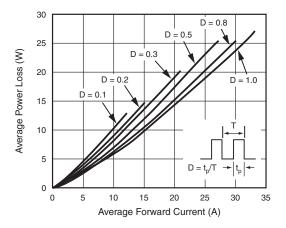


Fig. 2 - Forward Power Loss Characteristics Per Diode



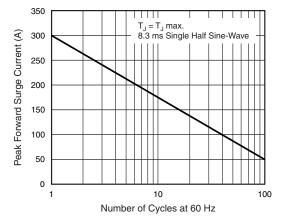


Fig. 3 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

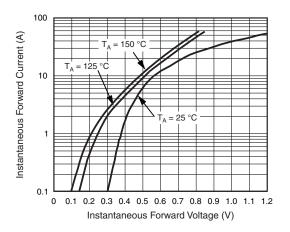


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode

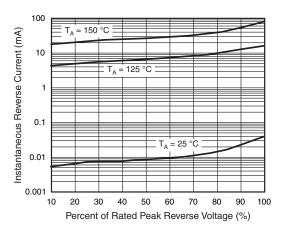


Fig. 5 - Typical Reverse Characteristics Per Diode

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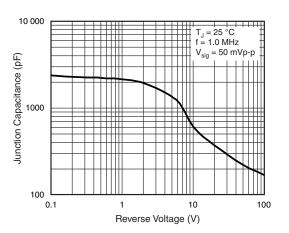


Fig. 6 - Typical Junction Capacitance Per Diode

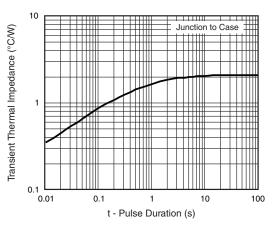


Fig. 7 - Typical Transient Thermal Impedance Per Diode

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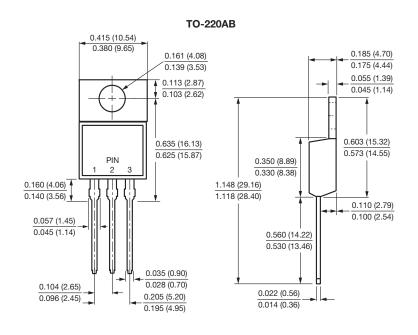
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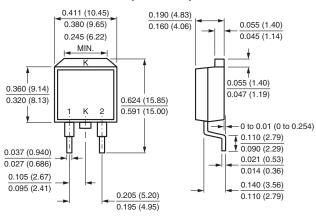




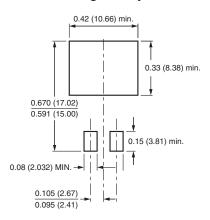
## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



D<sup>2</sup>PAK (TO-263AB)



**Mounting Pad Layout** 





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